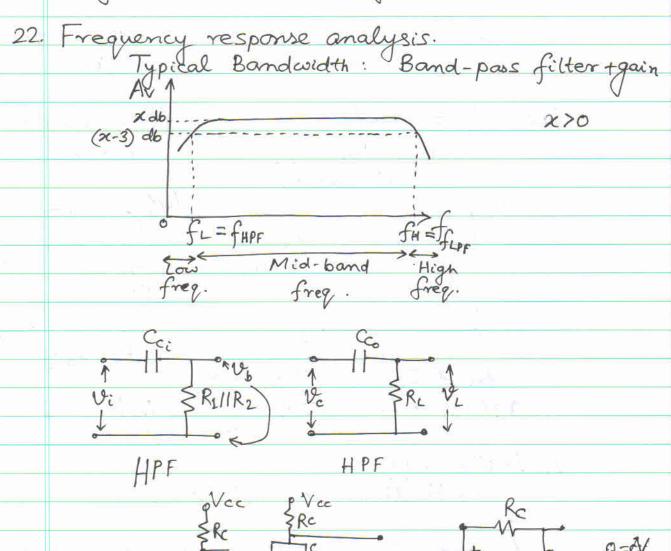
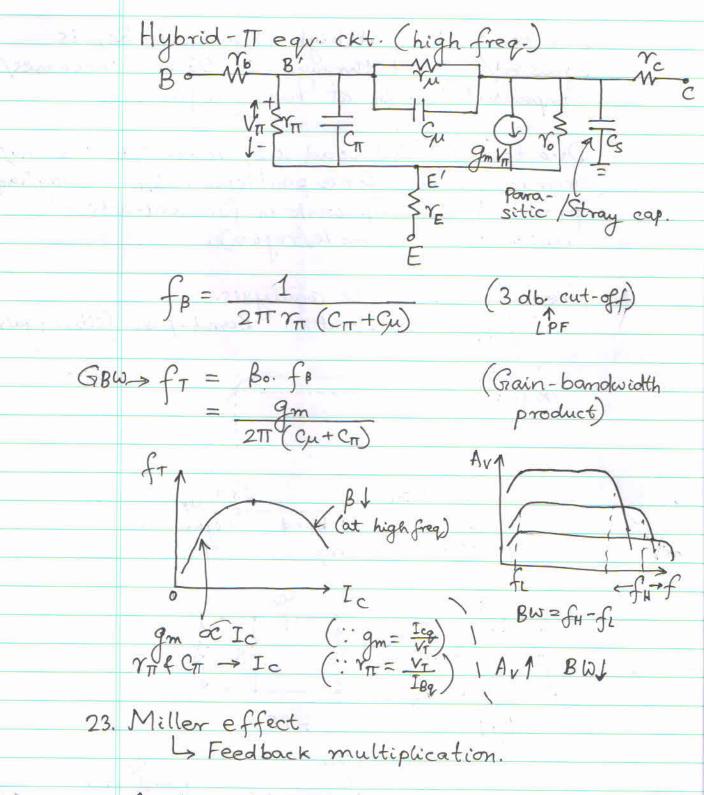


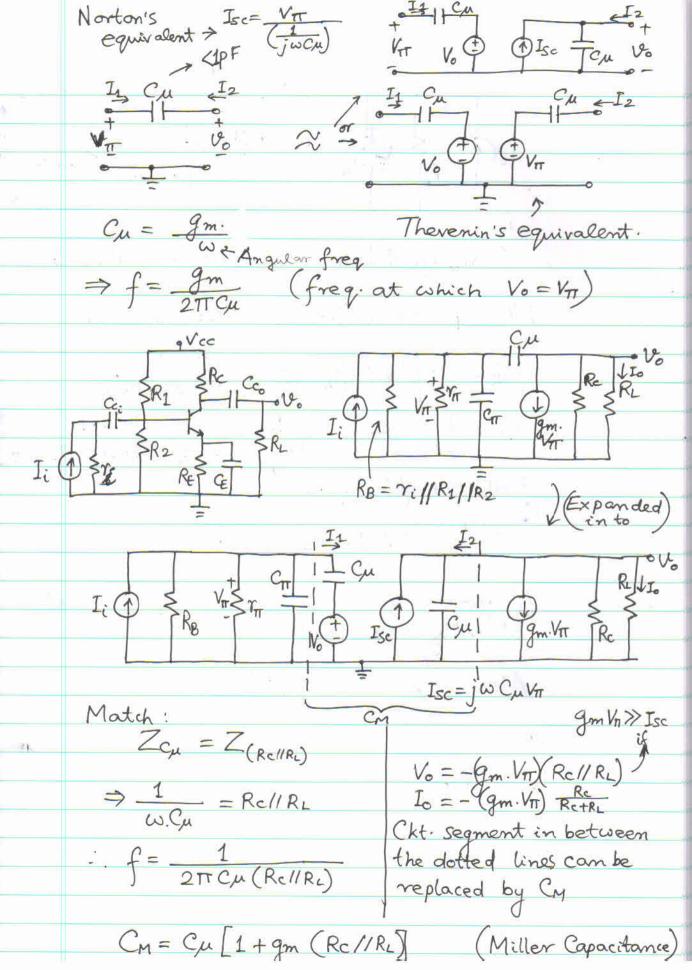
Due to CE//RE2, at high frequencies, RE2 is by passed/shorted through CE, therby increases/compensates gain at high frequencies.

Due to CE & AC load line, max. O/P V-swing/ range changes for a particular I/P V-swing/range, provided the amp. works in forward-active region (or linear mode/region).





At high freq, Cci, Cco & CE are considered to be short-circuited. And, Cu connects O/P to I/P. Cu > 2-port network.



Simplified hybrid-TT eqv. ckt. with Cu I/P capacitance, increased > CT + CM.  $V_{\pi} = I_{i} \left( \frac{R_{B}}{\gamma_{\pi}} \right) \left( \frac{1}{j \omega C_{\pi}} \right) \left( \frac{1}{j \omega C_{m}} \right) \right]$  $A_{i} = \frac{I_{o}}{I_{i}} = -g_{m} \left( \frac{R_{c}}{R_{c} + R_{L}} \right) \left[ \frac{R_{B} || r_{\pi}}{1 + j \omega \left( R_{B} || r_{\pi} \right) \left( C_{\pi} + C_{M} \right)} \right]$ 3 db cut-off freq.  $G = \frac{1}{2\pi(R_B//r_H)(C_H + C_M)}$ 

If you neglect Cu (or Cm = 0), the result is slightly inaccurate

Also, CM = Cu(1+ |AVI)